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TEST REPORT EN 50530

Overall efficiency of grid connected photovoltaic inverters

Report:

 Report Number.
 : 6041106.50

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Park Shibei Hi-Tech Park, Zhabei District, Shanghai 200436, China

Applicant's name Shenzhen SOFAR SOLAR Co., Ltd.

Xin'an Street, Bao'an District, Shenzhen, P.R. China

Test specification:

Standard.....: EN 50530:2010+A1:2013

Test Report Form No. EN50530_V1.0

Test Report Form(s) Originator: DEKRA Testing and Certification (Shanghai) Ltd.

Master TRF.....: Dated 2014-05

Test item description Grid-connected PV Inverter

Trade Mark::



Manufacturer: Shenzhen SOFAR SOLAR Co., Ltd.

5/F, Building 4, Antongda Industrial Park, No.1 Liuxian Avenue,

Xin'an Street, Bao'an District, Shenzhen, P.R. China

Ratings SOFAR 20000TL-G2:

PV input: Max.1100 Vdc, MPPT voltage range: 230-960 Vdc, MPPT full power voltage range: 480-850 Vdc, max 24/24 A, Isc PV: 30/30 A

Output: 400V, 3N~, 50 Hz, 20000 VA, max 3x32 A

SOFAR 25000TL-G2:

PV input: Max.1100 Vdc, MPPT voltage range: 230-960 Vdc, MPPT full power voltage range: 460-850 Vdc, max 28/28 A, Isc PV: 35/35 A

Output: 400V, 3N~, 50 Hz, 25000 VA, max 3x40 A

SOFAR 33000TL-G2:

PV input: Max.1100 Vdc, MPPT voltage range: 230-960 Vdc, MPPT

full power voltage range: 580-850 Vdc, max 30/30 A, Isc PV:

37.5/37.5 A

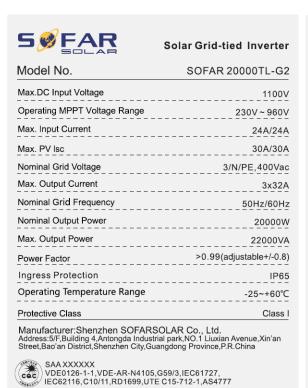
Output: 400V, 3N~, 50 Hz, 33000 VA, max 3x53 A

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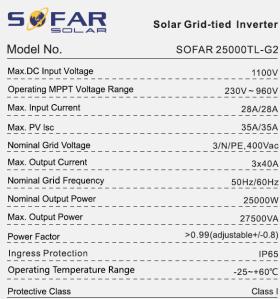
Resp	oonsible Testing Laboratory (as applica	ble), testing procedure	and testing location(s):		
\boxtimes	Testing Laboratory:	DEKRA Testing and Certification (Shanghai) Ltd.			
Test	ing location/ address:	3F, #250 Jiangchangsan Road, Building 16, Headquarter Economy Park Shibei Hi-Tech Park, Zhabei District, Shanghai 200436, China			
\boxtimes	Associated Testing Laboratory:	CQC-Trusted Testing Technology Co., Ltd.			
Test	ing location/ address:	No.99, Wenlan Road, 0	Qixia, Nanjing, Jiangsu, China		
Test	ed by (name, function, signature):	Jason Guo	Jasalon		
Аррі	roved by (name, function, signature):	Allan Chen	Sen		
	Testing procedure: CTF Stage 1:				
Tost	ing location/ address:				
1000	9 .000				
Test	ed by (name, function, signature):				
Аррі	roved by (name, function, signature):				
	Testing procedure: CTF Stage 2:				
Test	ing location/ address::				
Test	ed by (name + signature):				
Witn	essed by (name, function, signature).:				
Аррі	oved by (name, function, signature):				
	Testing presedures CTE Stone 2:				
	Testing procedure: CTF Stage 3:				
Testing procedure: CTF Stage 4:					
Testing location/ address:					
Tested by (name, function, signature):					
Witn	essed by (name, function, signature).:				
Аррі	oved by (name, function, signature):				
Supe	ervised by (name, function, signature):				

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Copy of marking plate:



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Manufacturer:Shenzhen SOFARSOLAR Co., Ltd. Address:5/F,Building 4,Antongda Industrial park,NO.1 Liuxian Avenue,Xin'an Street,Bao'an District,Shenzhen City,Guangdong Province,P.R.China



SAA XXXXXX VDE0126-1-1,VDE-AR-N4105,G59/3,IEC61727, IEC62116,C10/11,RD1699,UTE C15-712-1,AS4777















1100V
230V~960V
30A/30A
37.5A/37.5A
3/N/PE,400Vac
3x53A
50Hz/60Hz
33000W
36300VA
>0.99(adjustable+/-0.8)
IP65
-25~+60°C
Class I
R Co., Ltd. k,NO.1 Liuxian Avenue,Xin'an ng Province,P.R.China
F 1

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Test item particulars:	Grid-connected PV Inverter
Class of equipment:	Class I
Connection to the mains:	Permanent connection
IP protection class:	IP65
Possible test case verdicts:	
- test case does not apply to the test object	N/A
- test object does meet the requirement:	P (Pass)
- test object does not meet the requirement:	F (Fail)
- test object was not evaluated for the requirement	N/E
- this clause is information for reference only	Info.
Testing:	
Date of receipt of test item(s)	2018-09-28 (samples provided by applicant)
Dates tests performed	2018-09-28 to 2018-10-27
General remarks:	
The test results presented in this report relate only to th This report shall not be reproduced, except in full, without	

Name and address of factory (ies):

"(See attached table)" refers to a table appended to the report.

"(Appendix #)" refers to additional information appended to the report. List of test equipment must be kept on file and available for review.

Additional test data and/or information provided in the attachments to this report. Throughout this report a \square comma / \boxtimes point is used as the decimal separator.

laboratory.

Shenzhen SOFAR SOLAR Co., Ltd.

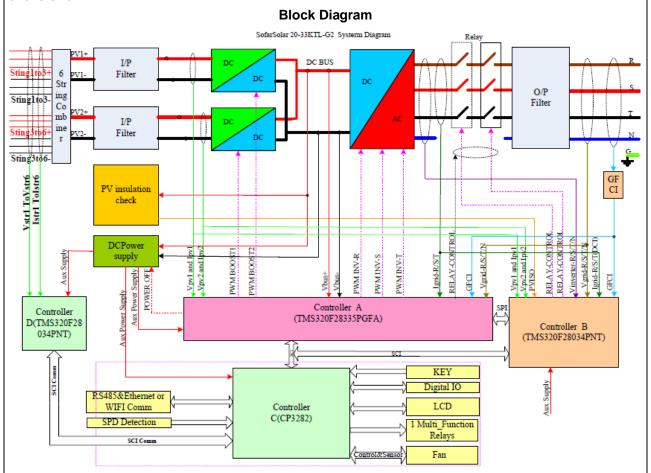
5/F, Building 4, Antongda Industrial Park, No.1 Liuxian Avenue, Xin'an Street, Bao'an District, Shenzhen , P.R. China

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General product information:

The three-phase Grid-connected PV Inverter converts DC voltage into AC voltage.

The unit is providing EMC filtering at the output toward mains. The unit does not provide galvanic separation from input to output (transformerless). The output is switched off redundant by the high power switching bridge and two relays. This assures that the opening of the output circuit will also operate in case of one error.



The internal control is redundant built. It consists of Main DSP and slave DSP.

The Main DSP can control the relays, measures voltage, and frequency, AC current with injected DC, insulation resistance and residual current; In addition it tests the array insulation resistance and the RCMU circuit before each start up.

The slave DSP is using for detect residual current, also can open the relays independently and communicate with Main DSP.

The unit provides two relays in series on Line conductors. When single-fault applied to one relay, alarm an error code in display panel, another redundant relay provides basic insulation maintained between the PV array and the mains. All the relays are tested before start up. Both controllers Main DSP, Slave DSP can open the relays.

The product was tested on:

Hardware version: V1.00 Software version: V1.40

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		EN 50530		
Clause	Requirement - Test		Result - Remark	Verdict

4	MPPT and conversion efficiencies	Р
4.1	General description	Р
	The MPPT efficiency describes the accuracy of an inverter to set its operating conditions to match the maximum power point on the characteristic curve of a PV generator. The MPPT efficiency is divided into the static and dynamic conditions.	Р
	As with inverters with poor MPPT performance, the resulting DC input voltage is different from MPP voltage and conversion efficiency depends on DC input voltage, measurements of static MPPT efficiency and static power conversion efficiency according to 4.3 shall be performed simultaneously (detailed explanation in the informative Annex F).	Р
	a) Static MPPT efficiency The static MPPT efficiency is determined by means of measurement as follows:	Р
	$\eta_{\mathit{MPPT:tat}} = \frac{1}{P_{\mathit{MPP,PVS}} \cdot T_M} \sum_i U_{\mathit{DC,i}} \cdot I_{\mathit{DC,i}} \cdot \Delta T$ The static MPPT efficiency describes the accuracy of an inverter to regulate on the maximum power point on a given static characteristic curve of a PV generator.	
	b) Dynamic MPPT efficiency Variations of the irradiation intensity and the resulting transition of the inverter to the new operation point are not considered with the static MPPT efficiency. For the evaluation of this transient characteristic the dynamic MPPT efficiency is specified. The dynamic MPPT efficiency is defined as: $\eta_{MPPTdyn} = \frac{1}{\sum_{j} P_{MPP,PVS,j} \cdot \Delta T_{j}} \sum_{i} U_{DC,j} \cdot I_{DC,j} \cdot \Delta T_{i}$	Р
4.2	Test set-up	Р
	The generic test set-up for single phase grid connected inverters is depicted in Figure 1. The diagram can also be considered as a single phase representation of a test-circuit for multi-phase inverters. PV. Simulator PD. PD. AC. Grid AC. Grid	P
	The DC source connected to the PV input of the inverter shall be a PV simulator in accordance to the specifications in Clause A.1.	Р

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	EN 50530		
Clause	Requirement - Test	Result - Remark	Verdict
	The AC supply of the inverter must be in accordance to the specifications in Clause A.2.		Р
	For the conversion efficiency, the DC and AC voltages shall be measured as close as possible to the inverter terminals. For MPPT efficiency, the DC voltage shall be measured as close as possible to the PV simulator. For combined conversion and MPPT efficiency measurements, two voltage measurements will be required at the output of the PVS and the DC input of the EUT, in order to avoid measurement errors resulting from the voltage drop between the PVS and the EUT.		Р
4.3	Conversion and static MPPT efficiency		Р
4.3.1	Test conditions		Р
	The measurement of the conversion and static MPPT efficiency shall be performed simultaneously with test specifications as defined in Table 1.		Р
	For test devices with several independent input terminals, the measurements must be performed for all input configurations as intended by the manufacturer. Unless otherwise provided by the manufacturer, the total power must be split equally on the individual input terminals.		P
	The measurement shall be performed at nominal grid voltage U _{AC,r} in order to avoid any impact of the grid voltage level on the measurement results. Deviations must be documented in the measurement report.		P
	The measurement should be performed at an ambient temperature of 25 °C ± 5 °C. Other ambient temperatures can be mutually agreed. The actual ambient temperature shall be specified in the test report.		Р
4.3.2	Measurement procedure		Р
	For each of the above specified test conditions a corresponding I/U characteristic has to be defined which must be emulated by means of the PV simulator.		Р
	After commissioning the device under test the stabilization of the MPP tracking must be awaited firstly.		Р
	The measuring time for each test condition as specified in Table 1 amounts to 10 min. For the first power level of each MPP voltage setting, the stabilisation of the MPPT-tracker has to be awaited. If a stabilisation cannot be observed a stabilisation time of at least 5 min is defined.		P
	After a change of the power level a general stabilisation period of 2 min should be used. Data recorded during the stabilisation periods are not to be considered for the calculation of the static MPPT and conversion efficiency.		Р

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Clause	Requirement - Test	Result - Remark	Verdict
	After the stabilisation of the MPP tracking the following parameters have to be logged: - PMPP,PVS; - PDC; - UMPP,PVS; - IMPP,PVS; - IDC; - PAC.		Р
4.3.3	Evaluation - Calculation of conversion and static MPPT efficiency		Р
	For each measured power level according to Table 1, the conversion η_{conv} and static MPPT efficiency η_{MPPT} shall be calculated as energetic averages according to the definitions 3.4.2 and 3.4.1. The results shall be documented in the measuring report for each test condition according to Table 1.	See attached table.	Р
	For each MPP voltage and each simulated I/U characteristic respectively the following particulars are to be calculated and documented in the measuring report:	See attached table.	Р
	 the weighted European MPPT efficiency according to Annex D.1 	See attached table.	Р
	 as well as the weighted CEC MPPT efficiency (California Energy Commission) according to Annex D.2. 	See attached table.	Р
	Furthermore, modifications of the internal setting of the device under test, conspicuous behaviour during the measurement as well as variations from the defined procedure are to be documented.		Р
4.4	Dynamic MPPT efficiency		Р
4.4.1	Dynamic MPPT efficiency		Р
	The measurement of the dynamic MPPT efficiency has to be performed according to the test conditions as outlined in the tables in Annex B.	See attached Table B.1 to Table B.3.	Р
	The dynamics of the test sequences are generated by changes in solar irradiance. Measurements shall be performed with c-Si PV model as a basis and can additionally be made with TF model (see Table C.1). The chosen model (PV technology) shall be documented in the report.		Р
	Dynamic MPPT efficiency test must be performed at rated DC voltage. For test devices with several independent input terminals, the measurements must be performed for all input configurations as intended by the manufacturer. Unless otherwise provided by the manufacturer, the total power must be split equally on the individual input terminals.		Р

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Clause	Requirement - Test	Result - Remark	Verdict				
	The measurement should be performed at an ambient temperature of 25 °C ± 5 °C. Other ambient temperatures can be mutually agreed. The actual ambient temperature shall be specified in the test report.		Р				
4.4.2	Measurement procedure		Р				
	For each of the test conditions specified in Annex B a corresponding I/V characteristic has to be defined which must be emulated by means of the PV simulator. A radiation intensity of 1 000 W/m² is related to the rated DC power PDC, r of the device under test. Previous to each test sequence a waiting period (initial set-up time) must be inserted in order to await the stabilization of the device under test. Values measured during this initial set-up time are not considered for calculation of the dynamic MPPT efficiency according to 4.4.3.		Р				
	For the evaluation and the determination of the dynamic MPPT efficiency the following parameters are to be recorded during the measurement: - PMPPPVS MPP power provided by the PV simulator; - PDC measured input power of the device under test; - UMPPPVS MPP voltage provided by the PV simulator; - UDC measured input voltage of the device under test; - IMPPPVS MPP current provided by the PV simulator; - IDC measured input current of the device under test.		Р				
4.4.3	Evaluation – Calculation of the dynamic MPPT efficiency		Р				
	The overall dynamic MPPT efficiency is the mean value of the single dynamic MPPT efficiencies of the test sequences according to tables B.1 and B.2. It is calculated by: $\eta_{\mathit{MPPTdyn,t}} = \frac{1}{N} \sum_{i=1}^{N} a_i \cdot \eta_{\mathit{MPPTdyn,i}} \\ - \eta_{\mathit{MPPTdyn,t}} \text{ averaged dynamic MPPT efficiency} \\ - \eta_{\mathit{MPPTdyn,l}} \text{ dynamic MPPT efficiency for each test sequence} \\ - N \text{ number of test sequences} \\ - a_i \text{ weighting factor}$		Р				
	For each test sequence according to Annex B the dynamic MPPT efficiency $\eta_{MPPT,dyn}$ is to be calculated based on the recorded data according the definition. The results are to be documented in the measuring report.	See attached table.	Р				
	For each test sequence the calculated MPPT efficiency is to be documented tabularly in the measuring report.	See attached table.	Р				

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Clause	Requirement - Test	Result - Remark	Verdict
	Furthermore, modifications of the internal setting of the device under test, conspicuous behaviour during the measurement as well as variations from the defined procedure are to be documented.		Р
5	Calculation of the overall efficiency		Р
	The DC power is converted to the AC power P _{AC} by means of the conversion efficiency η _{CONV} . The actual DC power P _{DC} of the device under test is the product from the static MPPT efficiency η _{MPPTstat} and the MPP power provided by the PV simulator P _{MPP, PVS} :	See attached table.	Р
	Pac = η _{conv} · P _{DC} = η _{conv} · η _{MPPTstat} · P _{MPP,PVS} = η _t · P _{MPP,PVS} The overall efficiency η _t can also be considered as: $ \eta_t = \eta_{conv} \cdot \eta_{MPPTstat} = \frac{P_{AC}}{P_{MPP,PVS}} \qquad Formula (8) $	See attached table.	Р
	Formula (8) is to be applied for each power and voltage level of Table 1. By the application of weighting factors of EUR and CEC according to D.1 and D.2, the efficiencies can summarised for each voltage level (U_{MPPmax} , $U_{\text{DC,r}}$, U_{MPPmin}). As a result, the weighted overall efficiencies $\eta_{\text{t,EUR}}$ and $\eta_{\text{t,CEC}}$ are obtained.	See attached table.	Р

4.3	TABLE: Conversion and static MPPT efficiency								Р
	Table 1 – Test specifications for the static MPPT efficiency								
Model	SOFAR 20000	TL-G2							
MPP voltage of the	Simulated I/V	MPP p	ower of		ated I/V power, P		ristic norm	alized to	o rated
simulated I/V characteristic	characteristic	5%	10%	20%	25%	30%	50%	75%	100%
onaracioneno				Stati	c MPPT	Efficienc	y (%)		
U _{MPPmax} , (850Vdc)	c-Si	97.05	99.73	95.37	99.97	99.91	99.83	99.70	98.06
U _{DC,r} (620Vdc)	c-Si	99.39	99.96	99.94	99.96	99.83	99.80	99.14	98.90
U _{MPPmin} (480Vdc)	c-Si	99.88	99.13	99.00	99.27	99.81	99.89	99.81	99.78
U _{MPPmax} , (850Vdc)	TF b)	98.96	97.62	99.92	99.63	99.93	99.83	99.75	99.43
U _{DC,r} (620Vdc)	TF ^{b)}	99.96	99.69	98.45	99.07	97.43	99.81	99.73	98.73
U _{MPPmin} (480Vdc)	TF ^{b)}	98.74	99.55	99.17	99.29	99.91	99.88	99.90	99.52
MPP voltage of the simulated I/V characteristic	Simulated I/V characteristic	Calculated of Static European MPPT efficiency (%) Calculated of Static CEC MPPT efficiency (%)							
U _{MPPmax} , (850Vdc)	c-Si		98	.81			99.	46	
U _{DC,r} (620Vdc)	c-Si		99	.64			99.	42	
U _{MPPmin} (480Vdc)	c-Si	99.70 99.76							
U _{MPPmax} , (850Vdc)	TF	99.61 99.70							
U _{DC,r} (620Vdc)	TF	99.18 99.36							
U _{MPPmin} (480Vdc)	TF		99	.66			99.	83	

Note:
The MPP voltages at the different test conditions (U_{MPPmax} , $U_{DC,r}$, U_{MPPmin}) shall be kept constant during the test for each power level.
The U_{MPPmax} , $U_{DC,r}$ and U_{MPPmin} was MPPT full power voltage declare by manufacturer.

4.3	TABLE: Conv	TABLE: Conversion and static MPPT efficiency							Р
Table 1 – Test specifications for the static MPPT efficiency									
Model	SOFAR 25000	SOFAR 25000TL-G2							
MPP voltage of the	Simulated I/V	MPP power of the simulated I/V characteristic normalized to rate DC power, P _{MPP,PVS} / P _{DC, r}					rated		
simulated I/V characteristic	characteristic	5%	10%	20%	25%	30%	50%	75%	100%
				Stati	MPPT Efficiency (%)				
U _{MPPmax} , (850Vdc)	c-Si	96.39	99.94	99.92	98.13	99.52	99.50	99.44	98.19
U _{DC,r} (620Vdc)	c-Si	99.46	99.66	99.71	99.81	99.90	99.78	99.86	99.83
U _{MPPmin} (460Vdc)	c-Si	99.33 99.83 99.93 99.83 99.82 99.86 99.95 99.95							
U _{MPPmax} , (850Vdc)	TF	99.16 99.28 99.96 99.90 99.97 99.91 99.89 98.64							
U _{DC,r} (620Vdc)	TF	99.44	99.67	99.83	99.81	99.84	99.74	99.89	99.83
U _{MPPmin} (460Vdc)	TF	99.87	99.84	99.95	99.98	99.73	99.85	99.87	99.86

MPP voltage of the simulated I/V characteristic	Simulated I/V characteristic	Calculated of Static European MPPT efficiency (%)	Calculated of Static CEC MPPT efficiency (%)
U _{MPPmax} , (850Vdc)	c-Si	99.23	99.44
U _{DC,r} (620Vdc)	c-Si	99.78	99.83
U _{MPPmin} (460Vdc)	c-Si	99.87	99.91
U _{MPPmax} , (850Vdc)	TF	99.61	99.82
U _{DC,r} (620Vdc)	TF	99.77	99.84
U _{MPPmin} (460Vdc)	TF	99.85	99.85

The MPP voltages at the different test conditions (U_{MPPmax} , $U_{DC,r}$, U_{MPPmin}) shall be kept constant during the test for each power level.

The U_{MPPmax} , $U_{DC,r}$ and U_{MPPmin} was MPPT full power voltage declare by manufacturer.

4.3	TABLE: Conv	ersion a	nd statio	MPPT e	efficienc	y			Р			
	Table 1 – Test specifications for the static MPPT efficiency											
Model	SOFAR 33000	SOFAR 33000TL-G2										
MPP voltage of the	Simulated I/V	MPP p	power of		ated I/V power, P		ristic norn P _{DC, r}	nalized to	o rated			
simulated I/V characteristic	characteristic	5%	10%	20%	25%	30%	50%	75%	100%			
				Stati	c MPPT	Efficiency	y (%)					
U _{MPPmax} , (850Vdc)	c-Si	98.10	99.01	99.96	99.97	99.97	99.95	99.84	99.22			
U _{DC,r} (620Vdc)	c-Si	99.89	99.88	99.87	99.88	99.92	99.99	99.99	99.76			
U _{MPPmin} (580Vdc)	c-Si	97.96	99.31	99.88	99.94	99.89	99.88	99.87	99.80			
U _{MPPmax} , (850Vdc)	TF	99.85	99.89	99.95	99.97	99.86	99.90	99.36	99.60			
U _{DC,r} (620Vdc)	TF	99.69	99.89	99.71	99.65	99.70	99.47	99.90	99.71			
U _{MPPmin} (580Vdc)	TF	99.57	98.38	99.80	99.90	99.87	99.83	99.87	99.82			
MPP voltage of the simulated I/V characteristic	Simulated I/V characteristic		lated of S			Calcula	ated of St efficier		MPPT			
U _{MPPmax} , (850Vdc)	c-Si		99	.70			99	82				
U _{DC,r} (620Vdc)	c-Si		99	.91			99	96				
U _{MPPmin} (580Vdc)	c-Si	99.77 99.85										
U _{MPPmax} , (850Vdc)	TF	99.84 99.60										
U _{DC,r} (620Vdc)	TF	99.60 99.77										
U _{MPPmin} (580Vdc)	TF		99	.73			99	80				

Note:

The MPP voltages at the different test conditions (U_{MPPmax} , $U_{DC,r}$, U_{MPPmin}) shall be kept constant during the test for each power level.

The U_{MPPmax} , $U_{DC,r}$ and U_{MPPmin} was MPPT full power voltage declare by manufacturer.

D.1 European efficiency

$$\begin{split} \eta_{\textit{MPPTstat},\textit{EUR}} &= a_{\text{EU}_1} \cdot \eta_{\textit{MPP}_1} + a_{\text{EU}_2} \cdot \eta_{\textit{MPP}_2} + a_{\text{EU}_3} \cdot \eta_{\textit{MPP}_3} + a_{\text{EU}_4} \cdot \eta_{\textit{MPP}_4} \\ &+ a_{\text{EU}_5} \cdot \eta_{\textit{MPP}_5} + a_{\text{EU}_6} \cdot \eta_{\textit{MPP}_6} \end{split}$$

Weighting	a _{EU_1}	a _{EU_2}	a _{EU_3}	a _{EU_4}	a _{EU_5}	a _{EU_6}
Factor	0.03	0.06	0.13	0.1	0.48	0.2
Partial MPP	MPP_1	MPP_2	MPP_3	MPP_4	MPP_5	MPP_6
P _{MPP,PVS} /P _{DC, r}	0.05	0.1	0.2	0.3	0.5	1

D.2 CEC efficiency

$$\begin{split} \eta_{\mathit{MPPTstat,CEC}} &= a_{\mathsf{CEC}_1} \cdot \eta_{\mathit{MPP}_1} + a_{\mathsf{CEC}_2} \cdot \eta_{\mathit{MPP}_2} + a_{\mathsf{CEC}_3} \cdot \eta_{\mathit{MPP}_3} + a_{\mathsf{CEC}_4} \cdot \eta_{\mathit{MPP}_4} \\ &+ a_{\mathsf{CEC}_5} \cdot \eta_{\mathit{MPP}_5} + a_{\mathsf{CEC}_6} \cdot \eta_{\mathit{MPP}_6} \end{split}$$

4.3	TABLE: Conv	ersion a	nd statio	MPPT 6	efficienc	/			P
	Table 2 -Test	specific	cation fo	r the co	nversion	efficien	су		
Model	SOFAR 20000	TL-G2							
MPP voltage of the	Simulated I/V	MPP p	ower of		ated I/V power, P		ristic norm	nalized to	o rated
simulated I/V characteristic	characteristic	5%	10%	20%	25%	30%	50%	75%	100%
		Conversion Efficiency (%)							
U _{MPPmax} , (850Vdc)	c-Si	91.26	94.05	96.15	96.50	96.73	97.03	97.02	97.27
U _{DC,r} (620Vdc)	c-Si	93.90	96.14	97.16	97.34	97.45	97.55	97.48	97.33
U _{MPPmin} (480Vdc)	c-Si	93.50	95.74	96.80	97.03	97.11	97.32	97.26	97.08
U _{MPPmax} , (850Vdc)	TF	90.94	94.55	96.21	96.61	96.76	97.04	97.04	96.94
U _{DC,r} (620Vdc)	TF	93.90	96.18	97.17	97.30	97.43	97.54	97.49	97.36
U _{MPPmin} (480Vdc)	TF	93.39	95.68	96.81	97.05	97.08	97.27	97.20	97.02
MPP voltage of the simulated I/V characteristic	Simulated I/V characteristic		lculated o			Calcul	ated of C efficien		ersion
U _{MPPmax} , (850Vdc)	c-Si		96	.58			96.	84	
U _{DC,r} (620Vdc)	c-Si		97	.25			97.	41	
U _{MPPmin} (480Vdc)	c-Si	i 96.97 97.16							
U _{MPPmax} , (850Vdc)	TF	96.55 96.86							
U _{DC,r} (620Vdc)	TF		97.25 97.42						
U _{MPPmin} (480Vdc)	TF		96	.93			97.	11	

The MPP voltages at the different test conditions (UMPPmax, UDC,r, UMPPmin) shall be kept constant during the test for each power level. The U_{MPPmin} was MPPT full power voltage declare by manufacturer.

4.3	TABLE: Conv	ersion a	nd statio	MPPT e	efficiency	/			Р	
	Table 2 –Test	specific	cation fo	r the cor	nversion	efficien	су			
Model	SOFAR 25000	TL-G2								
MPP voltage of the	Simulated I/V	MPP p	MPP power of the simulated I/V characteristic normalized to rated DC power, P _{MPP,PVS} / P _{DC, r}							
simulated I/V characteristic	characteristic	5%	10%	20%	25%	30%	50%	75%	100%	
		Conversion Efficiency (%)								
U _{MPPmax} , (850Vdc)	c-Si	92.43	94.99	96.59	96.80	96.98	97.14	97.11	97.02	
U _{DC,r} (620Vdc)	c-Si	95.34	97.03	97.78	97.94	98.01	98.01	97.94	97.73	
U _{MPPmin} (460Vdc)	c-Si	94.16	96.03	96.97	97.16	97.25	97.37	97.22	96.96	
U _{MPPmax} , (850Vdc)	TF	92.53 95.14 96.59 96.87 97.03 97.23 97.19 96.97								
U _{DC,r} (620Vdc)	TF	95.51 96.47 97.85 97.99 97.99 98.06 98.01 97.87								
U _{MPPmin} (460Vdc)	TF	94.20	96.03	96.94	97.14	97.24	97.36	97.21	96.94	

MPP voltage of the simulated I/V characteristic	Simulated I/V characteristic	Calculated of European Conversion efficiency (%)	Calculated of CEC Conversion efficiency (%)
U _{MPPmax} , (850Vdc)	c-Si	96.76	96.99
U _{DC,r} (620Vdc)	c-Si	97.79	97.91
U _{MPPmin} (460Vdc)	c-Si	97.05	97.18
U _{MPPmax} , (850Vdc)	TF	96.81	97.06
U _{DC,r} (620Vdc)	TF	97.82	97.94
U _{MPPmin} (460Vdc)	TF	97.03	97.17

The MPP voltages at the different test conditions (U_{MPPmax} , $U_{DC,r}$, U_{MPPmin}) shall be kept constant during the test for each power level.

The U_{MPPmax} , $U_{DC,r}$ and U_{MPPmin} was MPPT full power voltage declare by manufacturer.

4.3	TABLE: Conv	TABLE: Conversion and static MPPT efficiency							
	Table 2 -Test	specific	cation fo	r the co	nversion	efficien	су	•	
Model	SOFAR 33000	TL-G2							
MPP voltage of the	Simulated I/V	MPP p	power of		ated I/V opower, P		ristic norr P _{DC, r}	nalized to	o rated
simulated I/V characteristic	characteristic	5%	10%	20%	25%	30%	50%	75%	100%
				Con	version E	Efficiency	′ (%)		
U _{MPPmax} , (850Vdc)	c-Si	94.73	96.52	97.40	97.52	97.58	97.60	97.47	97.28
U _{DC,r} (620Vdc)	c-Si	96.31	97.57	98.01	98.06	98.10	98.06	97.89	97.68
U _{MPPmin} (580Vdc)	c-Si	95.40 97.07 97.66 97.70 97.74 97.69 97.46 97.22							
U _{MPPmax} , (850Vdc)	TF	94.55	96.55	97.47	97.59	97.64	97.63	97.47	97.28
U _{DC,r} (620Vdc)	TF	95.93	97.21	97.74	97.80	97.68	97.55	97.63	97.57
U _{MPPmin} (580Vdc)	TF	95.68	97.13	97.61	97.69	97.75	97.70	97.43	97.29
MPP voltage of the simulated I/V characteristic	Simulated I/V characteristic		lculated on version of			Calcul	ated of C efficier	EC Conv	ersion
U _{MPPmax} , (850Vdc)	c-Si		97	.36			97	.46	
U _{DC,r} (620Vdc)	c-Si		97	.90			97	.93	
U _{MPPmin} (580Vdc)	c-Si	97.49 97.52							
U _{MPPmax} , (850Vdc)	TF	97.38 97.48							
U _{DC,r} (620Vdc)	TF	97.52 97.60							
U _{MPPmin} (580Vdc)	TF		97	.52			97	.52	

Note:

The MPP voltages at the different test conditions (U_{MPPmax} , $U_{DC,r}$, U_{MPPmin}) shall be kept constant during the test for each power level.

The U_{MPPmax} , $U_{DC,r}$ and U_{MPPmin} was MPPT full power voltage declare by manufacturer.

D.1 European efficiency

$$\begin{split} \eta_{\mathit{MPPTstat},\mathit{EUR}} &= a_{\mathtt{EU}_1} \cdot \eta_{\mathit{MPP}_1} + a_{\mathtt{EU}_2} \cdot \eta_{\mathit{MPP}_2} + a_{\mathtt{EU}_3} \cdot \eta_{\mathit{MPP}_3} + a_{\mathtt{EU}_4} \cdot \eta_{\mathit{MPP}_4} \\ &+ a_{\mathtt{EU}_5} \cdot \eta_{\mathit{MPP}_5} + a_{\mathtt{EU}_6} \cdot \eta_{\mathit{MPP}_6} \end{split}$$

Weighting	a _{EU_1}	a _{EU_2}	a _{EU_3}	a _{EU_4}	a _{EU_5}	a _{EU_6}
Factor	0.03	0.06	0.13	0.1	0.48	0.2
Partial MPP	MPP_1	MPP_2	MPP_3	MPP_4	MPP_5	MPP_6
power P _{MPP,PVS} /P _{DC, r}	0.05	0.1	0.2	0.3	0.5	1

D.2 CEC efficiency

$$\begin{split} \eta_{\mathit{MPPTstat,CEC}} &= a_{\mathsf{CEC}_1} \cdot \eta_{\mathit{MPP}_1} + a_{\mathsf{CEC}_2} \cdot \eta_{\mathit{MPP}_2} + a_{\mathsf{CEC}_3} \cdot \eta_{\mathit{MPP}_3} + a_{\mathsf{CEC}_4} \cdot \eta_{\mathit{MPP}_4} \\ &+ a_{\mathsf{CEC}_5} \cdot \eta_{\mathit{MPP}_5} + a_{\mathsf{CEC}_6} \cdot \eta_{\mathit{MPP}_6} \end{split}$$

Weighting	a _{CEC_1}	a _{CEC_2}	a _{CEC_3}	a _{CEC_4}	a _{CEC_5}	a _{CEC_6}
Factor	0.04	0.05	0.12	0.21	0.53	0.05
Partial MPP	MPP_1	MPP_2	MPP_3	MPP_4	MPP_5	MPP_6
 power P _{MPP,PVS} /P _{DC, r}	0.1	0.2	0.3	0.5	0.75	1

4.4	TABLE: I	Dynamic MP	PT Efficiency	/			Р					
Tabl	e B.1 – Dyna	mic MPPT-T	est 10 % → 5	50 % _{Gsтс} (va	lid for the ev	valuation of η	MPPTdyn)					
Model												
Repetition Number	Slope (W/m²/s)	Ramp UP (s)	Dwell time (s)	Ramp DN (s)	Dwell time (s)	Duration (s)	Efficiency (%)					
2	0,5	800	10	800	10	3540	99.59					
2	1	400	10	400	10	1940	98.87					
3	2	200	10	200	10	1560	98.99					
4	3	133	10	133	10	1444	99.00					
6	5	80	10	80	10	1380	98.81					
8	7	57	10	57	10	1372	98.71					
10	10	40	10	40	10	1300	97.41					
10	14	29	10	29	10	1080	98.11					
10	20	20	10	20	10	900	98.20					
10	30	13	10	13	10	760	98.20					
10	50	8	10	8	10	660	98.06					
-	-	-	-	-	Total	15 936 s	-					
-	-	-	-	-	-	04:25:36 h	-					

Note:

4.4	TABLE: I	Dynamic MPI	PT Efficiency	/			Р		
Table	Table B.1 – Dynamic MPPT-Test 10 % $ ightarrow$ 50 % $G_{\rm STC}$ (valid for the evaluation of $\eta_{\rm MPPTdyn}$)								
Model	SOFAR 2	5000TL-G2							
Repetition	Slope	Slope Ramp UP Dwell time Ramp DN Dwell time Duration Efficiency							

Number	(W/m²/s)	(s)	(s)	(s)	(s)	(s)	(%)
2	0,5	800	10	800	10	3540	99.45
2	1	400	10	400	10	1940	98.65
3	2	200	10	200	10	1560	99.07
4	3	133	10	133	10	1444	98.39
6	5	80	10	80	10	1380	98.05
8	7	57	10	57	10	1372	99.22
10	10	40	10	40	10	1300	98.21
10	14	29	10	29	10	1080	98.16
10	20	20	10	20	10	900	98.33
10	30	13	10	13	10	760	97.44
10	50	8	10	8	10	660	98.27
-	-	-	-	-	Total	15 936 s	-
-	-	-	-	-	-	04:25:36 h	-

Ramp and dwell times are given as rounded values.

4.4	TABLE: I	Dynamic MP	PT Efficiency	/			Р					
Table	Table B.1 – Dynamic MPPT-Test 10 % $ ightarrow$ 50 % $G_{\rm STC}$ (valid for the evaluation of $\eta_{\rm MPPTdyn}$)											
Model	Model SOFAR 33000TL-G2											
Repetition Number	Slope (W/m²/s)	Ramp UP (s)	Dwell time (s)	Ramp DN (s)	Dwell time (s)	Duration (s)	Efficiency (%)					
2	0,5	800	10	800	10	3540	99.59					
2	1	400	10	400	10	1940	98.80					
3	2	200	10	200	10	1560	99.15					
4	3	133	10	133	10	1444	99.49					
6	5	80	10	80	10	1380	99.18					
8	7	57	10	57	10	1372	98.98					
10	10	40	10	40	10	1300	97.27					
10	14	29	10	29	10	1080	97.09					
10	20	20	10	20	10	900	97.35					
10	30	13	10	13	10	760	97.44					
10	50	8	10	8	10	660	95.86					
-	-	-	-	-	Total	15 936 s	-					
-	-	-	-	-	-	04:25:36 h	-					

Note:

4.4	TABLE: I	ABLE: Dynamic MPPT Efficiency								
Table	valuation of	η _{MPPTdyn})								
Model SOFAR 20000TL-G2										
Repetition Number	Slope (W/m²/s)	Ramp UP (s)	Dwell time (s)	Ramp DN (s)	Dwell time (s)	Duration (s)	Efficiency (%)			
10	10	70	10	70	10	1900	99.58			
10	14	50	10	50	10	1500	99.76			
10	20	35	10	35	10	1200	99.66			
10	30	23	10	23	10	960	99.66			
10	50	14	10	14	10	780	99.68			
10	100	7	10	7	10	640	99.83			
-	-	Total 6 980 s -								
-	-	01:56:20 h -								
Note:										

4.4	TABLE: I	TABLE: Dynamic MPPT Efficiency										
Table B.2 – Dynamic MPPT-Test 30 % $ ightarrow$ 100 % $G_{\rm STC}$ (valid for the evaluation of $\eta_{\rm MPPTdyn}$)												
Model SOFAR 25000TL-G2												
Repetition Number	Slope (W/m²/s)	Ramp UP (s)	Dwell time (s)	Ramp DN (s)	Dwell time (s)	Duration (s)	Efficiency (%)					
10	10	70	10	70	10	1900	97.97					
10	14	50	10	50	10	1500	98.17					
10	20	35	10	35	10	1200	98.15					
10	30	23	10	23	10	960	98.11					
10	50	14	10	14	10	780	98.03					
10	100	7	10	7	10	640	97.77					
-	-	-	-	-	Total	6 980 s	-					
-	-	-	-	-	-	01:56:20 h	-					
Note: Ramp and d												

4.4	TABLE: Dynamic MPPT E			Р						
Table	Table B.2 – Dynamic MPPT-Test 30 % $ ightarrow$ 100 % $G_{\rm STC}$ (valid for the evaluation of $\eta_{\rm MPPTdyn}$)									
Model	SOFAR 3	3000TL-G2								
Repetition Number	Slope (W/m²/s)									
10	10	70	10	70	10	1900	98.36			

40	4.4	50	40	50	40	4500	00.00
10	14	50	10	50	10	1500	98.28
10	20	35	10	35	10	1200	98.66
10	30	23	10	23	10	960	98.24
10	50	14	10	14	10	780	98.52
10	100	7	10	7	10	640	98.17
-	-	-	-	-	Total	6 980 s	1
-	-	-	-	-	-	01:56:20 h	-

4.4	TABLE: [ABLE: Dynamic MPPT Efficiency							
Table B.3 – Start-up and shut-down test with slow ramps									
Model	SOFAR 2	0000TL-G2							
Repetition Number	Slope (W/m²/s)								
1	0,1	980	30	980	30	2320	99.82		
-	-	-	-	-	Total	2 320 s	-		
-	-	00:38:40 h -							
Note:									

4.4	TABLE: I	TABLE: Dynamic MPPT Efficiency								
	Table B.3 – Start-up and shut-down test with slow ramps									
Model	SOFAR 2	5000TL-G2								
Repetition Number	Slope (W/m²/s)	Ramp UP (s)	Dwell time (s)	Ramp DN (s)	Dwell time (s)	Duration (s)	Efficiency (%)			
1	0,1	980	30	980	30	2320	99.76			
-	-	-	-	-	Total	2 320 s	-			
-	-	-	-	-	-	00:38:40 h	-			
Note:										

4.4	TABLE: [TABLE: Dynamic MPPT Efficiency								
	Table B.3 – Start-up and shut-down test with slow ramps									
Model	SOFAR 3	OFAR 33000TL-G2								
Repetition Number	Slope (W/m²/s)	Ramp UP (s)	Dwell time (s)	Ramp DN (s)	Dwell time (s)	Duration (s)	Efficiency (%)			
1	0,1	980	30	980	30	2320	99.14			
-	-	Total 2 320 s								
-	-	-	-	-	-	00:38:40 h	-			

5	TABLE: Overa	TABLE: Overall Efficiency P						Р	
Model	SOFAR 20000	TL-G2							
MPP voltage of the simulated I/V characteristic	Simulated I/V			$\eta_t = \eta_{cc}$	η_{MPP}		P _{AC}		
	characteristic	5%	10%	20%	25%	30%	50%	75%	100%
				0	verall Eff	iciency (9	%)		
U _{MPPmax} , (850Vdc)	c-Si	88.57	93.80	91.70	96.47	96.64	96.87	96.73	95.38
U _{DC,r} (620Vdc)	c-Si	93.33	96.10	97.10	97.30	97.28	97.35	96.64	96.26
U _{MPPmin} (480Vdc)	c-Si	93.39	94.91	95.83	96.32	96.93	97.21	97.08	96.87
U _{MPPmax} , (850Vdc)	TF	89.99	92.30	96.13	96.25	96.69	96.88	96.80	96.39
U _{DC,r} (620Vdc)	TF	93.86	95.88	95.66	96.40	94.93	97.35	97.23	96.12
U _{MPPmin} (480Vdc)	TF	92.21	95.25	96.01	96.36	96.99	97.15	97.10	96.55
MPP voltage of the simulated I/V characteristic	Simulated I/V characteristic	Calcula		verall Eu ncy (%)	ropean	Calc	ulated of efficien		CEC
U _{MPPmax} , (850Vdc)	c-Si		95	.44			96.	31	
U _{DC,r} (620Vdc)	c-Si		96	.90			96.	85	
U _{MPPmin} (480Vdc)	c-Si	96.68 96.93							
U _{MPPmax} , (850Vdc)	TF	96.18 96.57							
U _{DC,r} (620Vdc)	TF		96.45 96.79						
U _{MPPmin} (480Vdc)	TF		96	.61			96.	94	

Note:

The U_{MPPmax} , $U_{\text{DC,r}}$ and U_{MPPmin} was MPPT full power voltage declare by manufacturer.

5	TABLE: Overa	TABLE: Overall Efficiency							Р	
Model	SOFAR 25000	TL-G2	ΓL-G2							
MPP voltage of the simulated I/V characteristic	Simulated I/V			$\eta_t = \eta_{cc}$	_{mv} ·η _{MPP}		P _{AC}			
	characteristic	5%	10%	20%	25%	30%	50%	75%	100%	
		Overall Efficiency (%)								
U _{MPPmax} , (850Vdc)	c-Si	89.09	94.93	96.51	94.99	96.51	96.65	96.57	95.26	
U _{DC,r} (620Vdc)	c-Si	94.83	96.70	97.50	97.75	97.91	97.79	97.80	97.56	
U _{MPPmin} (460Vdc)	c-Si	93.53	95.87	96.90	96.99	97.07	97.23	97.17	96.91	
U _{MPPmax} , (850Vdc)	TF	91.75	94.45	96.55	96.77	97.00	97.14	97.08	95.65	
U _{DC,r} (620Vdc)	TF	94.98	96.15	97.68	97.80	97.83	97.81	97.90	97.70	
U _{MPPmin} (460Vdc)	TF	94.08	95.88	96.89	97.12	96.98	97.21	97.08	96.80	
MPP voltage of the simulated I/V	Simulated I/V characteristic	Calcula	ated of O efficier	verall Eu ncy (%)	ropean	Calc	ulated of efficier		CEC	

characteristic			
U _{MPPmax} , (850Vdc)	c-Si	96.01	96.45
U _{DC,r} (620Vdc)	c-Si	97.57	97.74
U _{MPPmin} (460Vdc)	c-Si	96.92	97.09
U _{MPPmax} , (850Vdc)	TF	96.43	96.88
U _{DC,r} (620Vdc)	TF	97.59	97.78
U _{MPPmin} (460Vdc)	TF	96.89	97.03

The U_{MPPmax} , $U_{\text{DC,r}}$ and U_{MPPmin} was MPPT full power voltage declare by manufacturer.

5	TABLE: Overa	TABLE: Overall Efficiency P							Р
Model	SOFAR 33000	TL-G2							
MPP voltage of the simulated I/V characteristic	Simulated I/V			$\eta_t = \eta_c$	$_{onv}\cdot\eta_{MPI}$	$P_{Tstat} = \frac{1}{P_{Tstat}}$	P _{AC} MPP,PVS	=	
	characteristic	5%	10%	20%	25%	30%	50%	75%	100%
				С	verall Ef	ficiency (%)		
U _{MPPmax} , (850Vdc)	c-Si	92.93	95.56	97.36	97.49	97.55	97.55	97.31	96.52
U _{DC,r} (620Vdc)	c-Si	96.20	97.45	97.88	97.94	98.02	98.05	97.88	97.45
U _{MPPmin} (580Vdc)	c-Si	93.45	96.40	97.54	97.64	97.63	97.57	97.33	97.02
U _{MPPmax} , (850Vdc)	TF	94.41	96.44	97.42	97.56	97.50	97.53	96.85	96.89
U _{DC,r} (620Vdc)	TF	95.63	97.10	97.46	97.46	97.39	97.03	97.53	97.29
U _{MPPmin} (580Vdc)	TF	95.27	95.56	97.41	97.59	97.62	97.53	97.30	97.11
MPP voltage of the simulated I/V characteristic	Simulated I/V characteristic	Calcula	ated of O efficier	verall Euncy (%)	ropean	Cald		f Overall ncy (%)	CEC
U _{MPPmax} , (850Vdc)	c-Si		97	.06			97	7.28	
U _{DC,r} (620Vdc)	c-Si		97	.81			97	7.89	
U _{MPPmin} (580Vdc)	c-Si	97.27 97.37							
U _{MPPmax} , (850Vdc)	TF	97.23 97.08							
U _{DC,r} (620Vdc)	TF	97.14 97.38							
U _{MPPmin} (580Vdc)	TF		97	.25			97	'.31	

Note:

The U_{MPPmax} , $U_{\text{DC},r}$ and U_{MPPmin} was MPPT full power voltage declare by manufacturer.

The DC power is converted to the AC power P_{AC} by means of the conversion efficiency η_{conv} . The actual DC power P_{DC} of the device under test is the product from the static MPPT efficiency $\eta_{MPPTstat}$ and the MPP power provided by the PV simulator $P_{MPP, PVS}$:

$$P_{AC} = \eta_{conv} \cdot P_{DC} = \eta_{conv} \cdot \eta_{MPPTstat} \cdot P_{MPP,PVS} = \eta_{t} \cdot P_{MPP,PVS}$$
(7)

The overall efficiency η_t can also be considered as

$$\eta_t = \eta_{conv} \cdot \eta_{MPPTstat} = \frac{P_{AC}}{P_{MPP,PVS}}$$
(8)

D.1 European efficiency

$$\begin{split} \eta_{\textit{MPPTstat}, \textit{EUR}} &= a_{\text{EU}_1} \cdot \eta_{\textit{MPP}_1} + a_{\text{EU}_2} \cdot \eta_{\textit{MPP}_2} + a_{\text{EU}_3} \cdot \eta_{\textit{MPP}_3} + a_{\text{EU}_4} \cdot \eta_{\textit{MPP}_4} \\ &+ a_{\text{EU}_5} \cdot \eta_{\textit{MPP}_5} + a_{\text{EU}_6} \cdot \eta_{\textit{MPP}_6} \end{split}$$

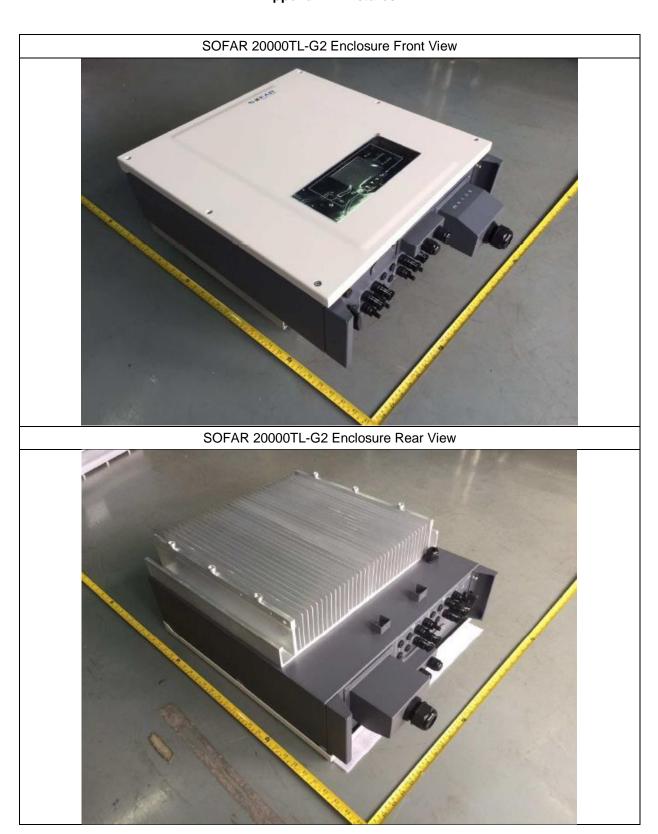
Weighting	a _{EU_1}	a _{EU_2}	a _{EU_3}	a _{EU_4}	a _{EU_5}	a _{EU_6}
Factor	0.03	0.06	0.13	0.1	0.48	0.2
Partial MPP	MPP_1	MPP_2	MPP_3	MPP_4	MPP_5	MPP_6
P _{MPP,PVS} /P _{DC, r}	0.05	0.1	0.2	0.3	0.5	1

D.2 CEC efficiency

$$\begin{split} \eta_{\mathit{MPPTstat,CEC}} = & \ a_{\mathtt{CEC}_1} \cdot \eta_{\mathit{MPP}_1} + a_{\mathtt{CEC}_2} \cdot \eta_{\mathit{MPP}_2} + a_{\mathtt{CEC}_3} \cdot \eta_{\mathit{MPP}_3} + a_{\mathtt{CEC}_4} \cdot \eta_{\mathit{MPP}_4} \\ & + a_{\mathtt{CEC}_5} \cdot \eta_{\mathit{MPP}_5} + a_{\mathtt{CEC}_6} \cdot \eta_{\mathit{MPP}_6} \end{split}$$

Weighting Factor	a _{CEC_1}	a _{CEC_2}	a _{CEC_3}	a _{CEC_4}	a _{CEC_5}	a _{CEC_6}
	0.04	0.05	0.12	0.21	0.53	0.05
Partial MPP power P _{MPP,PVS} /P _{DC, r}	MPP_1	MPP_2	MPP_3	MPP_4	MPP_5	MPP_6
	0.1	0.2	0.3	0.5	0.75	1

Appendix 1: Pictures



SOFAR 20000TL-G2 Enclosure Bottom View



SOFAR 20000TL-G2 Internal View







SOFAR 25000TL-G2 Enclosure Bottom View



SOFAR 25000TL-G2 Internal View







SOFAR 33000TL-G2 Enclosure Bottom View



SOFAR 33000TL-G2 Internal View



Appendix 2: List of test equipment used:

No.	Testing / measuring equipment	Туре	Internal no.	manufacturer	Calibration due date
1	AC simulator	RS90	CTTEQ-4	AMETEK EIG	2019-03-20
2	PV simulator	TC/P/32	CTTEQ-1	Regatron AG	2019-03-20
3	PV simulator	TC/P/32	CTTEQ-2	Regatron AG	2019-03-20
4	Power analyzer	WT3000	CEETQ-5	Yokogawa	2019-01-16
5	Current sensor	CT6863	CTTEQ-90	HOIKI	2019-03-15
6	Current sensor	CT6863	CTTEQ-92	HOIKI	2019-03-15
7	Current sensor	CT6863	CTTEQ-94	HOIKI	2019-03-15
8	Current sensor	CT6863	CTTEQ-95	HOIKI	2019-03-15
9	Temperature and hu midity Meter	608-H1	CTTEQ-189	Testo	2019-05-03
10	Air pressure gauge	DYM3	CTTEQ-77	Ningbo Yinzhou Jiangshan Glass Instruments factory	2019-03-06

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